

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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SPECIFICATION

(Reference sheet)

· Supplier : Samsung electro-mechanics · Samsung P/N: CL05A225KO5NQNC

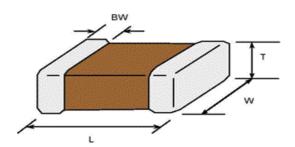
· Product : Multi-layer Ceramic Capacitor · Description : CAP, 2.2uF, 16V, ±10%, X5R, 0402

A. Samsung Part Number

<u>CL</u> <u>05</u> <u>A</u> <u>225</u> <u>K</u> <u>O</u> <u>5</u> <u>N</u> <u>Q</u> <u>N</u> <u>C</u> 1 2 3 4 5 6 7 8 9 10 11

1	Series	Samsung Multi-layer Ceramic Capacitor					
2	Size	0402 (inch code)	L: 1.00 ± 0.10 mr	m W:	$0.50 \pm 0.10 \text{ mm}$		
3	Dielectric	X5R	® Inner el	lectrode	Ni		
4	Capacitance	2.2 uF	Termin	ation	Cu		
⑤	Capacitance	±10 %	Plating		Sn 100% (Pb Free)		
	tolerance		9 Produc	t	Size control code		
6	Rated Voltage	16 V	® Special		Reserved for future use		
7	Thickness	$0.50 \pm 0.10 \text{ mm}$	① Packag	ing	Cardboard Type, 7" reel		

B. Structure & Dimension



Samsung P/N	Dimension(mm)				
Samsung F/N	L	W	Т	BW	
CL05A225KO5NQNC	1.00 ± 0.10	0.50 ± 0.10	0.50 ± 0.10	0.25 ± 0.10	

C. Samsung Reliablility Test and Judgement Condition

	boot		
Tan δ (DF) 0.1 max. treated at 150 °C +0/-10 °C for 1 hour and maintaine ambient air for 24±2 hours. Insulation 10,000Mohm or 100Mohm×μF Rated Voltage 60~120 sec. Whichever is smaller Appearance No abnormal exterior appearance Microscope (×10) Withstanding No dielectric breakdown or Voltage Temperature X5R Characteristics (From-55 °C to 85 °C, Capacitance change should be within ±15%) Adhesive Strength of Termination Bending Strength Capacitance change: within ±12.5% Bending to the limit (1mm) with 1.0mm/sec.	boot		
Resistance Whichever is smaller Appearance No abnormal exterior appearance Microscope (×10) Withstanding No dielectric breakdown or mechanical breakdown 250% of the rated voltage Voltage Microscope (×10) Voltage Mechanical breakdown Temperature X5R Characteristics (From-55 ℃ to 85 ℃, Capacitance change should be within ±15%) Adhesive Strength No peeling shall be occur on the formulation 500g·f, for 10±1 sec. Fermination Bending Strength Capacitance change : within ±12.5% Bending to the limit (1mm) with 1.0mm/sec.	*A capacitor prior to measuring the capacitance is heat treated at 150°C+0/-10°C for 1 hour and maintained in ambient air for 24±2 hours.		
Appearance No abnormal exterior appearance Microscope (×10) Withstanding No dielectric breakdown or Voltage Temperature Characteristics (From-55°C to 85°C, Capacitance change should be within ±15%) Adhesive Strength of Termination Bending Strength Capacitance change: within ±12.5% Bending to the limit (1mm) with 1.0mm/sec.			
Withstanding No dielectric breakdown or voltage 250% of the rated voltage Voltage mechanical breakdown X5R Characteristics (From-55℃ to 85℃, Capacitance change should be within ±15%) Adhesive Strength of Termination No peeling shall be occur on the terminal electrode 500g·f, for 10±1 sec. Bending Strength Capacitance change : within ±12.5% Bending to the limit (1mm) with 1.0mm/sec.			
Voltage mechanical breakdown Temperature X5R Characteristics (From-55 ℃ to 85 ℃, Capacitance change should be within ±15%) Adhesive Strength of Termination No peeling shall be occur on the terminal electrode 500g·f, for 10±1 sec. Bending Strength Capacitance change : within ±12.5% Bending to the limit (1mm) with 1.0mm/sec.	Microscope (×10)		
Temperature X5R Characteristics (From-55 ℃ to 85 ℃, Capacitance change should be within ±15%) Adhesive Strength of Termination No peeling shall be occur on the terminal electrode 500g·f, for 10±1 sec. Bending Strength Capacitance change : within ±12.5% Bending to the limit (1mm) with 1.0mm/sec.			
Temperature X5R Characteristics (From-55℃ to 85℃, Capacitance change should be within ±15%) Adhesive Strength of Termination No peeling shall be occur on the terminal electrode 500g·f, for 10±1 sec. Bending Strength Capacitance change : within ±12.5% Bending to the limit (1mm) with 1.0mm/sec.			
Adhesive Strength of Termination Bending Strength Capacitance change: within ±12.5% No peeling shall be occur on the terminal electrode Bending Strength Capacitance change: within ±12.5% Bending to the limit (1mm) with 1.0mm/sec.			
Adhesive Strength of Termination Bending Strength Capacitance change: within ±12.5% Bending Strength Wo peeling shall be occur on the terminal electrode Soug·f, for 10±1 sec. Bending to the limit (1mm) with 1.0mm/sec.			
Bending Strength Capacitance change: within ±12.5% Bending to the limit (1mm) with 1.0mm/sec.			
with 1.0mm/sec.			
Solderability More than 75% of terminal surface SnAg3.0Cu0.5 solder			
is to be soldered newly 245±5°C, 3±0.3sec.			
(preheating : 80~120°C for 10~30sec.)			
Resistance to Capacitance change: within ±7.5% Solder pot: 270±5℃, 10±1sec.			
Soldering Heat Tan δ, IR : initial spec.			
Vibration TestCapacitance change : within \pm 5%Amplitude : 1.5mmTan δ, IR : initial spec.From 10Hz to 55Hz (return : 1min.)2hours \times 3 direction (x, y, z)			
Moisture Capacitance change: within ±12.5% With rated voltage			
Resistance Tan δ : 0.2 max 40±2℃, 90~95%RH, 500+12/-0hrs			
IR : 500Mohm or 12.5Mohm × <i>μ</i> F			
Whichever is smaller			
High Temperature Capacitance change: within ±12.5% With 100% of the rated voltage			
Resistance Tan δ: 0.2 max Max. operating temperature			
IR : 1,000Mohm or 25Mohm × <i>μ</i> F 1000+48/-0hrs			
Whichever is smaller			
Temperature Capacitance change: within ±7.5% 1 cycle condition			
Cycling Tan δ , IR: initial spec. Min. operating temperature \rightarrow 25°C			
→ Max. operating temperature → 25°C	l.		
5 cycle test			

X The reliability test condition can be replaced by the corresponding accelerated test condition.

D. Recommended Soldering method:

Reflow (Reflow Peak Temperature : 260+0/-5°C, 10sec. Max)



A Product specifications included in the specifications are effective as of March 1, 2013.

Please be advised that they are standard product specifications for reference only.

We may change, modify or discontinue the product specifications without notice at any time.

So, you need to approve the product specifications before placing an order.

Should you have any question regarding the product specifications,

please contact our sales personnel or application engineers.

- Disclaimer & Limitation of Use and Application -

The products listed in this Specification sheet are **NOT** designed and manufactured for any use and applications set forth below.

Please note that any misuse of the products deviating from products specifications or information provided in this Spec sheet may cause serious property damages or personal injury.

We will **NOT** be liable for any damages resulting from any misuse of the products, specifically including using the products for high reliability applications as listed below.

If you have any questions regarding this 'Limitation of Use and Application', you should first contact our sales personnel or application engineers.

- ① Aerospace/Aviation equipment
- ② Automotive or Transportation equipment (vehicles, trains, ships, etc)
- 3 Medical equipment
- Military equipment
- 5 Disaster prevention/crime prevention equipment
- Any other applications with the same as or similar complexity or reliability to the applications set forth above.